

## Features

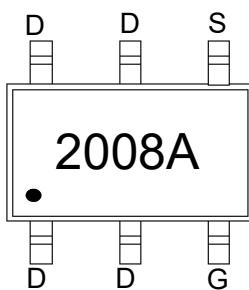
- Trench Power LV MOSFET technology
  - High Power and current handing capability

## Product Summary

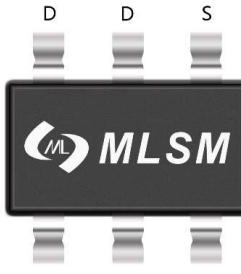
$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
20V	20m $\Omega$ @4.5V	7.6A
	27m $\Omega$ @2.5V	

## Application

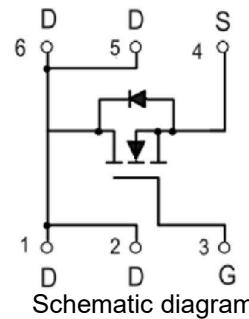
- PWM application
  - Load switch



## 2008A: Device code



## SOT-23-6L top view



## Schematic diagram

## Marking and pin assignment



The HAL logo consists of the letters "HAL" in white, bold, sans-serif font, enclosed within a thick blue circle. A diagonal slash from the top right corner through the center of the circle crosses over the letters.

## Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)				
Symbol	Parameter	Rating	Unit	
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
V <sub>DS</sub>	Drain-Source Breakdown Voltage	20	V	
V <sub>GS</sub>	Gate-Source Voltage	±12	V	
T <sub>J</sub>	Maximum Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature Range	-50 to 155	°C	
I <sub>S</sub>	Diode Continuous Forward Current	T <sub>c</sub> =25°C	7.6	A
<b>Mounted on Large Heat Sink</b>				
I <sub>DM</sub>	Pulse Drain Current Tested	T <sub>c</sub> =25°C	30	A
I <sub>D</sub>	Continuous Drain Current	T <sub>c</sub> =25°C	7.6	A
P <sub>D</sub>	Maximum Power Dissipation	T <sub>c</sub> =25°C	1.25	W
R <sub>θJA</sub>	Thermal Resistance Junction-to-Ambient		325	°C/W

Ordering Information (Example)						
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSL2008A	SOT-23-6L	2008A	3,000	45,000	180,000	7"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	20	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.45	0.7	1.2	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =4.5V, I <sub>D</sub> =7.6A	--	13.5	20	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =7.0A	--	17	27	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	885	--	pF
C <sub>OSS</sub>	Output Capacitance		--	135	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	120	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =10V, I <sub>D</sub> =7.6A, V <sub>GS</sub> =4.5V	--	11	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	1.75	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	3	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =10V, R <sub>L</sub> =1.5Ω, V <sub>GS</sub> =4.5V, R <sub>G</sub> =3Ω	--	7	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	45	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	30	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	50	--	nS
<b>Source-Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =7.6A	--	--	1.2	V

### Typical Operating Characteristics

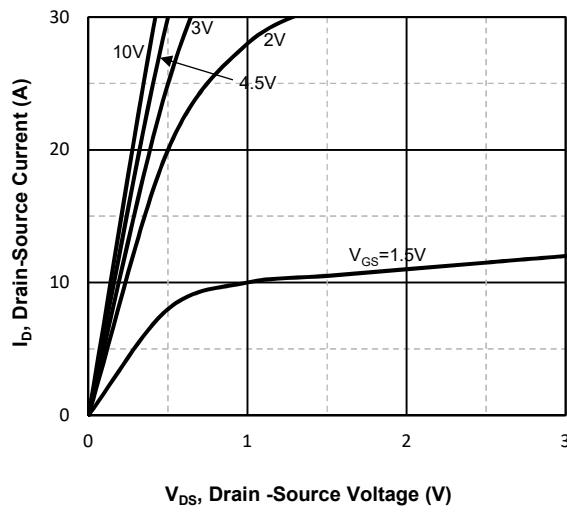


Fig1. Typical Output Characteristics

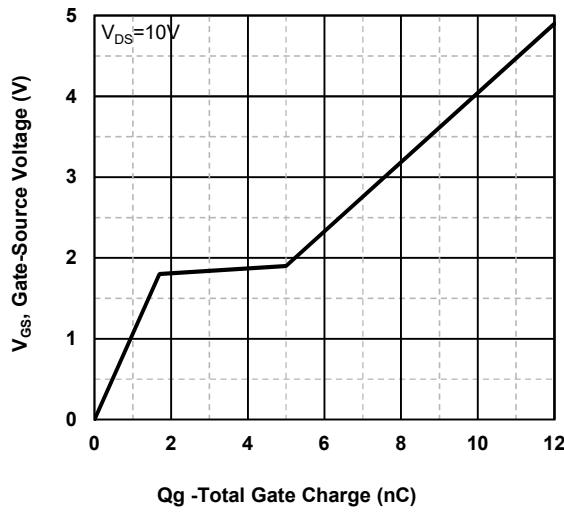


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

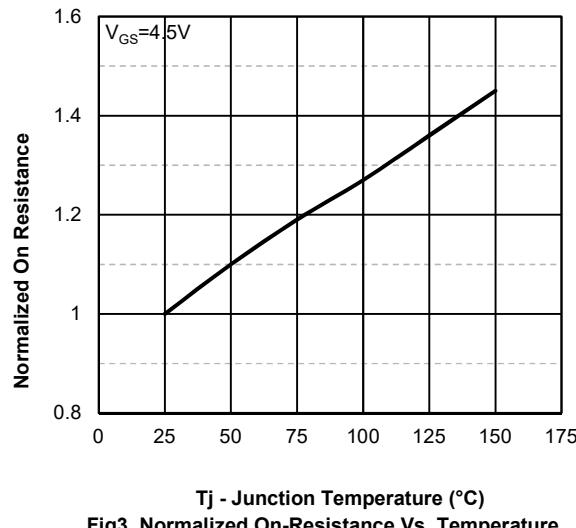


Fig3. Normalized On-Resistance Vs. Temperature

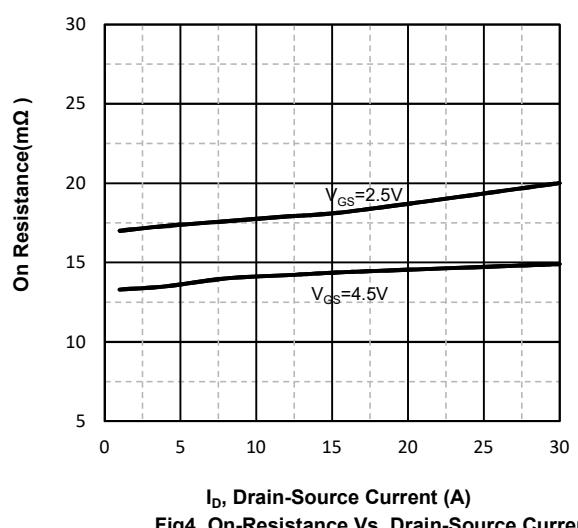


Fig4. On-Resistance Vs. Drain-Source Current

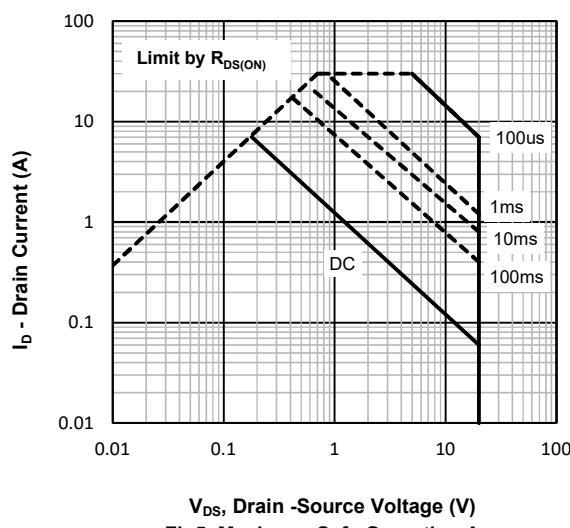


Fig5. Maximum Safe Operating Area

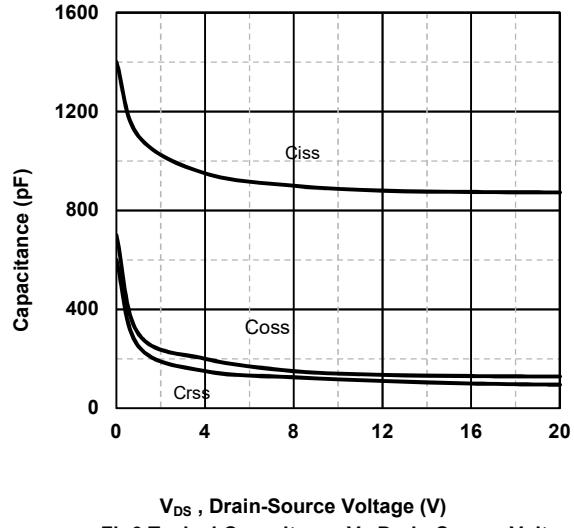
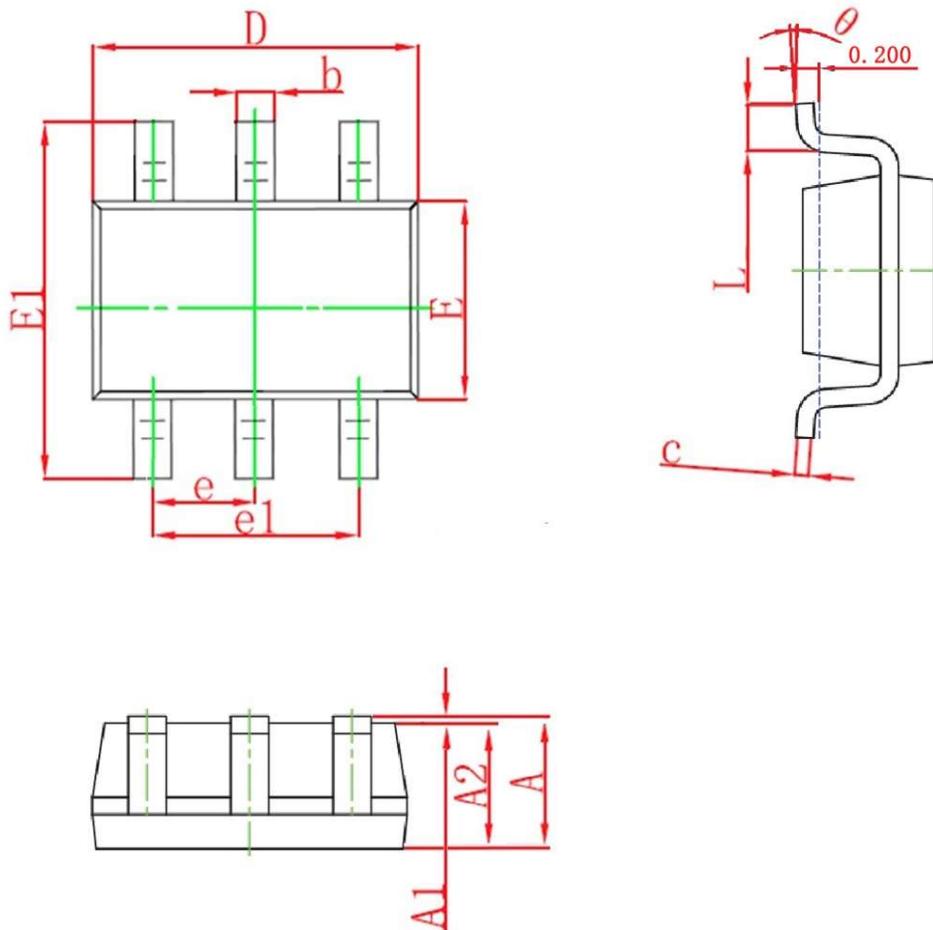


Fig6 Typical Capacitance Vs.Drain-Source Voltage

**SOT-23-6L Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.000	1.200	0.039	0.047
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.600	3.000	0.102	0.118
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
K	0°	8°	0°	8°